

TRANSISTOR

2N967

Germanium p-n-p type used in high-speed saturated switching applications in industrial data-processing equipment. JEDEC No. TO-18 package; outline 12, Outlines Section. This type is identical with type

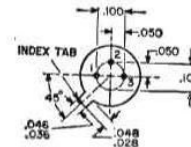
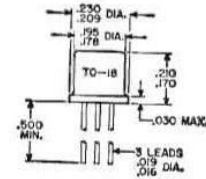
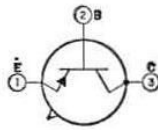
2N963 except for the following items:

CHARACTERISTICS

In Common-Emitter Circuit

DC Forward Current-Transfer Ratio (with collector-to-emitter volts = -0.3 and collector ma = -10)

40 min



- 12 -

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